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- 150-mA Load Current Without External Power Transistor
- Adjustable Current-Limiting Capability
- Input Voltages up to 40 V
- Output Adjustable From 2 V to 37 V
- Direct Replacement for Fairchild µA723C

#### description

The  $\mu$ A723 is a precision integrated-circuit voltage regulator, featuring high ripple rejection,

NC **I**NC 14 CURR LIM 13 FREQ COMP 2 CURR SENS [] 3 12 🛛 V<sub>CC+</sub> Ιv<sub>c</sub>  $IN - \Pi 4$ 11 IN+ [ 10 5 REF 9 🛛 V<sub>Z</sub> 6 8 🛛 NC V<sub>CC</sub>-

D OR N PACKAGE (TOP VIEW)

excellent input and load regulation, excellent temperature stability, and low standby current. The circuit consists of a temperature-compensated reference-voltage amplifier, an error amplifier, a 150-mA output transistor, and an adjustable-output current limiter.

The  $\mu$ A723 is designed for use in positive or negative power supplies as a series, shunt, switching, or floating regulator. For output currents exceeding 150 mA, additional pass elements can be connected as shown in Figures 4 and 5.

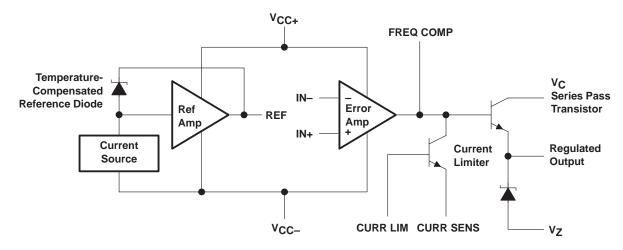
The  $\mu$ A723C is characterized for operation from 0°C to 70°C.

	PACKAGE	СНІР	
TA	PLASTIC DIP (N)	SMALL OUTLINE (D)	FORM (Y)
0°C to 70°C	μA723CN	μA723CD	μA723Y

AVAILABLE OPTIONS

The D package is available taped and reeled. Add the suffix R to the device type (e.g.,  $\mu$ A723CDR). Chip forms are tested at 25°C.

#### functional block diagram





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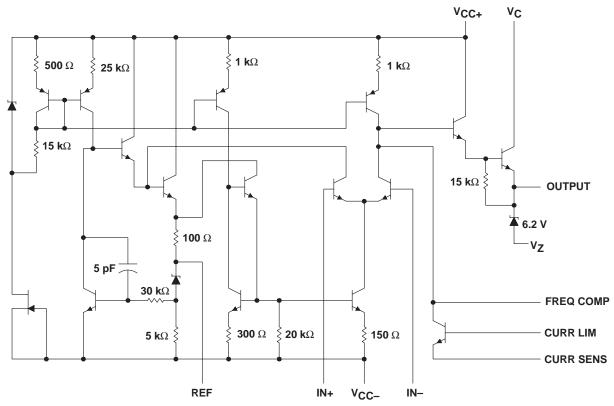
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#### schematic



Resistor and capacitor values shown are nominal.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Peak voltage from V <sub>CC+</sub> to V <sub>CC-</sub> ( $t_w \le 50$ ms)	50 V
Continuous voltage from V <sub>CC+</sub> to V <sub>CC-</sub>	40 V
Input-to-output voltage differential	40 V
Differential input voltage to error amplifier	±5 V
Voltage between noninverting input and V <sub>CC</sub>	
Current from V <sub>Z</sub>	
Current from REF	
Package thermal impedance, $\theta_{JA}$ (see Notes 1 and 2): D package	86°C/W
N package	. 101°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or N package	260°C
Storage temperature range, T <sub>stg</sub> 65°	C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can impact reliability.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.



#### recommended operating conditions

		MIN	MAX	UNIT
Input voltage, V <sub>I</sub>		9.5	40	V
Output voltage, VO		2	37	V
Input-to-output voltage differential, $V_C - V_O$		3	38	V
Output current, IO			150	mA
Operating free-air temperature range, T <sub>A</sub>	μA723C	0	70	°C

#### electrical characteristics at specified free-air temperature (see Notes 3 and 4)

PARAMETER	TEST CONDITIONS		TA	μ <b>Α723C</b>			UNIT		
PARAMETER				MIN	TYP	MAX			
	$V_I = 12 V$ to $V_I = 15 V$		25°C		0.1	1	1		
Input regulation	$V_I = 12 V$ to $V_I = 40 V$		25°C		1	5	mV/V		
	$V_I = 12 \text{ V to } V_I = 15 \text{ V}$		0°C to 70°C			3	1		
Ripple rejection	f = 50 Hz to 10 kHz,	$C_{ref} = 0$	25°C		74		dB		
	f = 50 Hz to 10 kHz,	$C_{ref} = 5 \ \mu F$	25°C		86				
Output regulation			25°C		-0.3	-2	mV/V		
Output regulation			0°C to 70°C			-6			
Reference voltage, V <sub>ref</sub>			25°C	6.8	7.15	7.5	V		
Standby current	V <sub>I</sub> = 30 V,	I <mark>O</mark> = 0	25°C		2.3	4	mA		
Temperature coefficient of output voltage			0°C to 70°C		0.003	0.015	%/°C		
Short-circuit output current	R <sub>SC</sub> = 10 Ω,	VO = 0	25°C		65		mA		
	BW = 100 Hz to 10 kHz,	$C_{ref} = 0$	25°C		20		μV		
Output noise voltage	BW = 100 Hz to 10 kHz,	$C_{ref} = 5 \ \mu F$	25°C		2.5				

NOTES: 3. For all values in this table, the device is connected as shown in Figure 1 with the divider resistance as seen by the error amplifier  $\leq 10 \text{ k}\Omega$ . Unless otherwise specified,  $V_I = V_{CC+} = V_C = 12 \text{ V}$ ,  $V_{CC-} = 0$ ,  $V_O = 5 \text{ V}$ ,  $I_O = 1 \text{ mA}$ ,  $R_{SC} = 0$ , and  $C_{ref} = 0$ .

4. Pulse-testing techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

## electrical characteristics, $T_A = 25^{\circ}C$ (see Notes 3 and 4)

PARAMETER	TEST CONDIT	μ <b>Α723Υ</b>			LINUT		
PARAMETER	TEST CONDIT	MIN	TYP	MAX	UNIT		
Input regulation	$V_{I} = 12 V \text{ to } V_{I} = 15 V$			0.1		mV/V	
	$V_{I} = 12 V \text{ to } V_{I} = 40 V$		1			mv/v	
Bipple rejection	f = 50 Hz to 10 kHz,	C <sub>ref</sub> = 0		74		dB	
Ripple rejection	f = 50 Hz to 10 kHz,	C <sub>ref</sub> = 5 μF		86		uБ	
Output regulation				-0.3		mV/V	
Reference voltage, V <sub>ref</sub>				7.15		V	
Standby current	VI = 30 V,	IO = 0		2.3		mA	
Short-circuit output current	R <sub>SC</sub> = 10 Ω,	VO = 0		65		mA	
Output noise voltage	BW = 100 Hz to 10 kHz,	C <sub>ref</sub> = 0		20		μV	
	BW = 100 Hz to 10 kHz,	$C_{ref} = 5 \ \mu F$		2.5		μv	

NOTES: 3. For all values in this table, the device is connected as shown in Figure 1 with the divider resistance as seen by the error amplifier  $\leq$  10 k $\Omega$ . Unless otherwise specified, V<sub>I</sub> = V<sub>CC+</sub> = V<sub>C</sub> = 12 V, V<sub>CC-</sub> = 0, V<sub>O</sub> = 5 V, I<sub>O</sub> = 1 mA, R<sub>SC</sub> = 0, and C<sub>ref</sub> = 0.

4. Pulse-testing techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.



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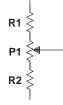
OUTPUT VOLTAGE	APPLICABLE FIGURES	FIXED OUTPUT ±5%		OUTPUT ADJUSTABLE $\pm 10\%$ (SEE NOTE 6)		
(V)	(SEE NOTE 5)	R1 (kΩ)	<b>R2</b> (kΩ)	<b>R1</b> (kΩ)	<b>Ρ1</b> (kΩ )	<b>Ρ2</b> (kΩ)
3.0	1, 5, 6, 9, 11, 12 (4)	4.12	3.01	1.8	0.5	1.2
3.6	1, 5, 6, 9, 11, 12 (4)	3.57	3.65	1.5	0.5	1.5
5.0	1, 5, 6, 9, 11, 12 (4)	2.15	4.99	0.75	0.5	2.2
6.0	1, 5, 6, 9, 11, 12 (4)	1.15	6.04	0.5	0.5	2.7
9.0	2, 4, (5, 6, 9, 12)	1.87	7.15	0.75	1.0	2.7
12	2, 4, (5, 6, 9, 12)	4.87	7.15	2.0	1.0	3.0
15	2, 4, (5, 6, 9, 12)	7.87	7.15	3.3	1.0	3.0
28	2, 4, (5, 6, 9, 12)	21.0	7.15	5.6	1.0	2.0
45	7	3.57	48.7	2.2	10	39
75	7	3.57	78.7	2.2	10	68
100	7	3.57	105	2.2	10	91
250	7	3.57	255	2.2	10	240
-6 (see Note 7)	3, 10	3.57	2.43	1.2	0.5	0.75
-9	3, 10	3.48	5.36	1.2	0.5	2.0
-12	3, 10	3.57	8.45	1.2	0.5	3.3
-15	3, 10	3.57	11.5	1.2	0.5	4.3
-28	3, 10	3.57	24.3	1.2	0.5	10
-45	8	3.57	41.2	2.2	10	33
-100	8	3.57	95.3	2.2	10	91
-250	8	3.57	249	2.2	10	240

## Table 1. Resistor Values (k $\Omega$ ) for Standard Output Voltages

**APPLICATION INFORMATION** 

NOTES: 5. The R1/R2 divider can be across either V<sub>O</sub> or V<sub>(ref)</sub>. If the divider is across  $V_{(ref)}$ , use the figure numbers without parentheses. If the divider is across V<sub>O</sub>, use the figure numbers in parentheses.

V<sub>O</sub>, use the figure numbers in parentheses.
6. To make the voltage adjustable, the R1/R2 divider shown in the figures must be replaced by the divider shown below.



#### Adjustable Output Circuit

7. For Figures 3, 8, and 10, the device requires a minimum of 9 V between V<sub>CC+</sub> and V<sub>CC-</sub> when V<sub>O</sub> is equal to or more positive than -9 V.



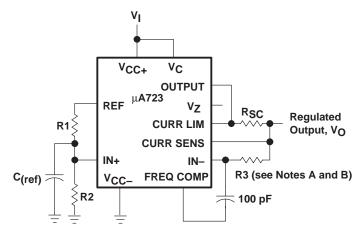
#### **APPLICATION INFORMATION**

#### Table 2. Formulas for Intermediate Output Voltages

OUTPUTS FROM 2 V TO 7 V SEE FIGURES 1, 5, 6, 9, 11, 12 (4) AND NOTE 5	OUTPUTS FROM 4 V TO 250 V SEE FIGURE 7 AND NOTE 5	CURRENT LIMITING
$V_{O} = V_{(ref)} \times \frac{R2}{R1 + R2}$	$V_{O} = \frac{V_{(ref)}}{2} \times \frac{R2 - R1}{R1}$ R3 = R4	$I_{(limit)} \approx \frac{0.65 \text{ V}}{\text{R}_{\text{SC}}}$
OUTPUTS FROM 7 V TO 37 V SEE FIGURES 2, 4, (5, 6, 9, 11, 12) AND NOTE 5	OUTPUTS FROM –6 V TO –250 V SEE FIGURES 3, 8, 10 AND NOTES 5 AND 7	FOLDBACK CURRENT LIMITING SEE FIGURE 6
$V_0 = V_{(ref)} \times \frac{R1 + R2}{R2}$	$V_{O} = -\frac{V_{(ref)}}{2} \times \frac{R1 + R2}{R1}$ R3 = R4	$I_{(knee)} \approx \frac{V_0 R3 + (R3 + R4) \ 0.65 \ V}{R_{SC} R4}$ $I_{OS} \approx \frac{0.65 \ V}{R_{SC}} \times \frac{R3 + R4}{R4}$

NOTES: 5. The R1/R2 divider can be across either VO or V(ref). If the divider is across V(ref), use figure numbers without parentheses. If the divider is across  $V_{O}$ , use the figure numbers in parentheses.

7. For Figures 3, 8, and 10, the device requires a minimum of 9 V between V<sub>CC+</sub> and V<sub>CC-</sub> when V<sub>O</sub> is equal to or more positive than -9 V.

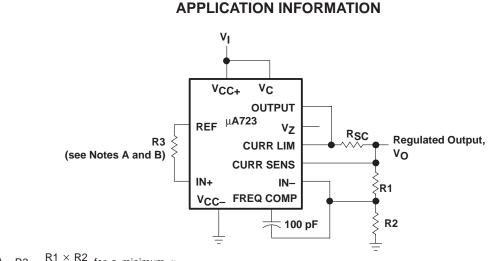


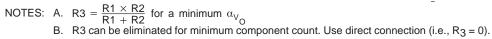
NOTES: A. R3 =  $\frac{R1 \times R2}{R1 + R2}$  for a minimum  $\alpha_{V_0}$ B. R3 can be eliminated for minimum component count. Use direct connection (i.e., R<sub>3</sub> = 0).

## Figure 1. Basic Low-Voltage Regulator ( $V_0 = 2 V \text{ to } 7 V$ )



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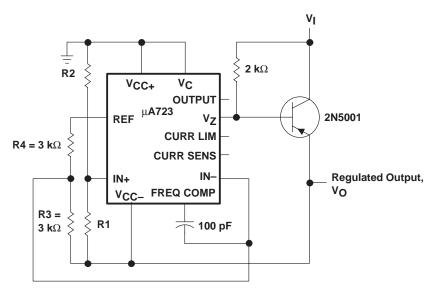


Figure 3. Negative-Voltage Regulator



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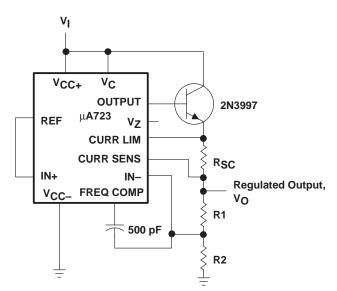


Figure 4. Positive-Voltage Regulator (External npn Pass Transistor)

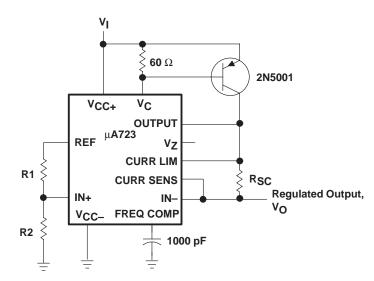


Figure 5. Positive-Voltage Regulator (External pnp Pass Transistor)



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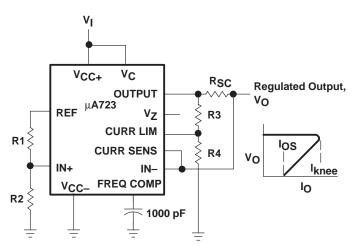


Figure 6. Foldback Current Limiting

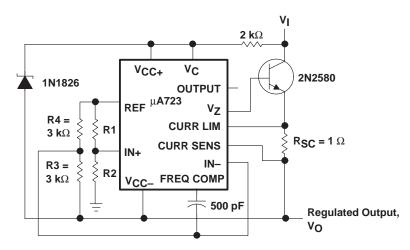


Figure 7. Positive Floating Regulator



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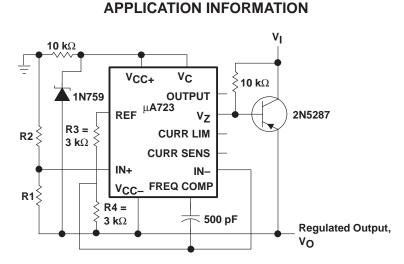
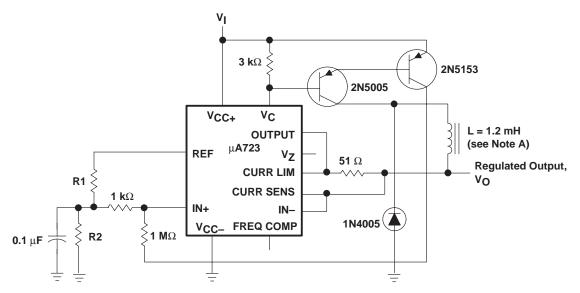


Figure 8. Negative Floating Regulator

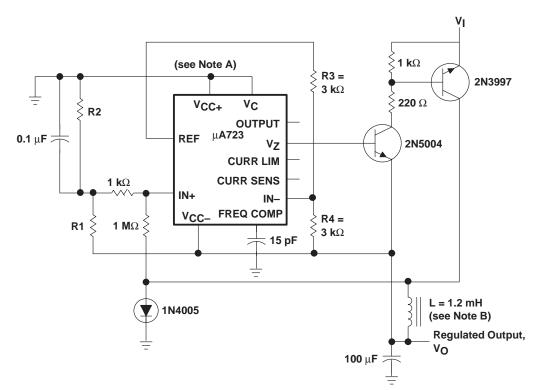


NOTE A: L is 40 turns of No. 20 enameled copper wire wound on Ferroxcube P36/22-3B7 potted core, or equivalent, with a 0.009-inch air gap.

Figure 9. Positive Switching Regulator



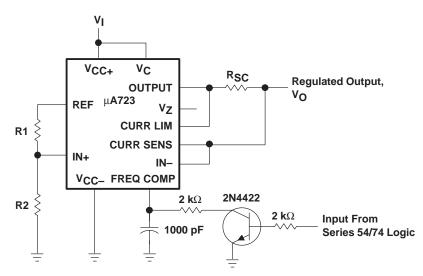
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**APPLICATION INFORMATION** 

NOTES: A. The device requires a minimum of 9 V between V<sub>CC+</sub> and V<sub>CC-</sub> when V<sub>O</sub> is equal to or more positive than -9 V.
B. L is 40 turns of No. 20 enameled copper wire wound on Ferroxcube P36/22-3B7 potted core, or equivalent, with a 0.009-inch air gap.

Figure 10. Negative Switching Regulator



NOTE A: A current-limiting transistor can be used for shutdown if current limiting is not required.

Figure 11. Remote Shutdown Regulator With Current Limiting



# $\mu \text{A723} \\ \textbf{PRECISION VOLTAGE REGULATORS} \\$

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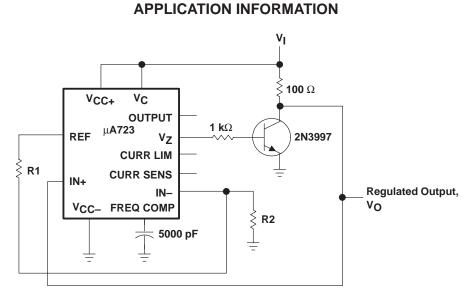


Figure 12. Shunt Regulator



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